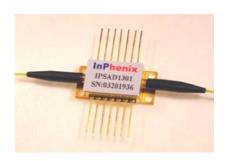
# **INPHENIX**

# Semiconductor Optical Amplifier Device (Gain-type)

### IPSAD1301/ IPSAD1501 (1310nm/1550nm)

#### **Features**

- Wide Optical Bandwidth
- High Saturation Output Power
- Low Polarization Sensitivity
- Low Gain Ripple
- MQW or Bulk Structure



### **Applications**

- Booster Amplifier (B-type)
- In-line Amplifier (L-type)
- Loss Compensation for Optical Cross-connect

### **IPSAD1301 Gain-type SOA Device Specifications**

Parameter	Symbol	B-type		L-type			Unit	
		Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Drive Current	$I_{F}$		250			250		mA
Peak Wavelength	$\lambda_{\rm p}$	1280		1340	1280		1340	nm
3 dB Optical Bandwidth	$\Delta \lambda_{3 ext{dB}}$	55			45			nm
Small Signal Gain @ λ <sub>p</sub>	$G_{max}$	13	16		18	22		dB
Gain Ripple with Respect to λ	ΔG		0.5	1.0		0.5	1.0	dB
Saturation Output Power	P <sub>sat</sub>	10				10		dBm
Polarization Dependent Gain	PDG		0.5	1.0		0.5	1.0	dB
Noise Figure	NF		7	7.5		7	7.5	dB

### **IPSAD1501 Gain-type SOA Device Specifications**

Parameter	Symbol	B-type		L-type			Unit	
		Min.	Typ.	Max.	Min.	Тур.	Max.	Unit
Drive Current	$I_{F}$		250			250		mA
Peak Wavelength	$\lambda_{\mathrm{p}}$	1510		1590	1510		1590	nm
3 dB Optical Bandwidth	$\Delta \lambda_{3 ext{dB}}$	55			45			nm
Small Signal Gain @ λ <sub>p</sub>	$G_{max}$	12	15		18	20		dB
Gain Ripple with Respect to λ	ΔG		0.5	1.0		0.5	1.0	dB
Saturation Output Power	P <sub>sat</sub>		10			10		dBm
Polarization Dependent Gain	PDG		0.5	1.0		0.5	1.0	dB
Noise Figure	NF			9.0			9.0	dB

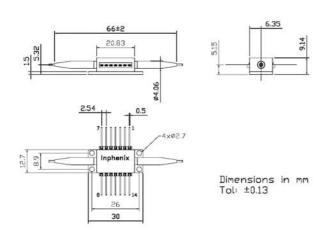
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### **Absolute Maximum Ratings**

Parameter	Min.	Max.	Unit		
Operating Temperature	-20	70	°C		
Storage Temperature	- 40	85	°C		
SOA Forward Current		300	mA		
SOA Reverse Voltage		2.5	V		
TEC Drive Current		1.5	A		
TEC Drive Voltage		3.6	V		
Thermistor Resistance	10 kΩ @ 25 °C				
SOA Chip Temperature Setting	25 °C				
Fiber Type	SMF				
Fiber Jacket	900 μ	900 μm or 250 μm tight buffer			
Package	14-pin Butterfly				

## **Package Dimensions**

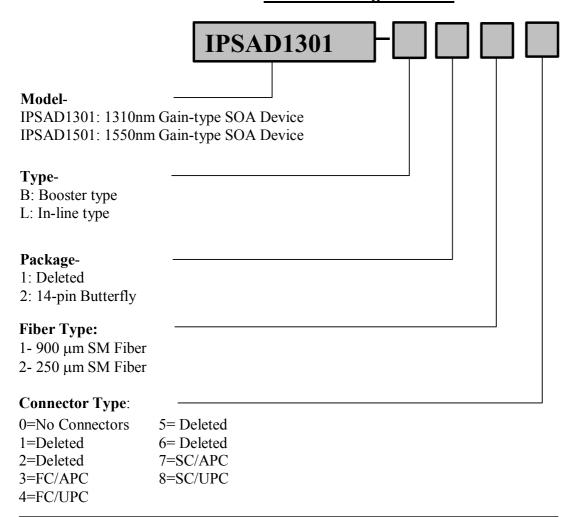


### **Pin Definition**

Pin	14-pin Butterfly			
1	TEC(+)			
2	NC			
3	Thermistor			
4	Thermistor			
5	NC			
6	NC			
7	NC			
8	NC			
9	NC			
10	SOA(+)			
11	SOA(-)			
12	NC			
13	Case			
14	TEC(-)			



### **Part Numbering Structure**



**Example**: IPSAD1301-L210: 1310 nm Gain-type In-line Amplifier SOA in 14-pin Butterfly Package with 900 µm SM Fiber with no Connectors.

#### **Corporate Office**

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